

SVD validation and calibration

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The validation package

- ▶ I have revived the validation package and made it work, see:

`svn/trunk/software/svd/validation/`

while the new DQM module is at:

`svn/trunk/software/svd/modules/svdDQM/`

- ▶ The validation plots can be found at:

<https://belle2.cc.kek.jp/validation/>

they use 1000 simulated and reconstructed events generated with the EvtGen module

- ▶ These plots show some anomalies in the simulation and reconstruction of events (documented in these slides).

The validation module contains:

- ▶ Cluster size
- ▶ Cluster charge
- ▶ Seed charge
- ▶ Pull: $(x_{cluster} - x_{hit})/\Delta x_{cluster}$
- ▶ Interstrip position:
 $(x_{cluster} \% p)/p$ ($p = \text{pitch}$)
- ▶ Digit charge (digits)
- ▶ Signal to noise (digits)
- ▶ dE/dx (simhits)
- ▶ Lost energy vs Deposited energy (truehits)
- ▶ Efficiency (truehits)

Events are divided based on:

- ▶ Layer
- ▶ Direction
- ▶ Sensor type
- ▶ Angle

The DQM module

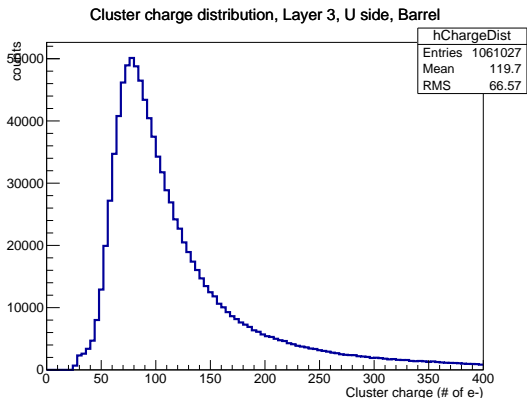
- ▶ I have added the Data Quality Monitoring module to the framework
- ▶ This monitoring is done online, need to be careful with size :
 - ▶ Problems at DESY beam test (total size of ≈ 100 MB)
 - ▶ Avoid the use of 2D histograms
 - ▶ Choose a not-too-fine binning

The DQM module contains

- ▶ Fired strips per event
- ▶ Clusters per event
- ▶ Hitmap (u and v, barrel and slanted)
- ▶ Digit charge
- ▶ Cluster charge
- ▶ Seed charge
- ▶ Size (u and v)
- ▶ Total: 44 histograms
- ▶ Only 1D histograms

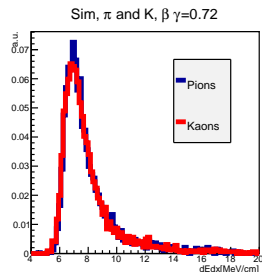
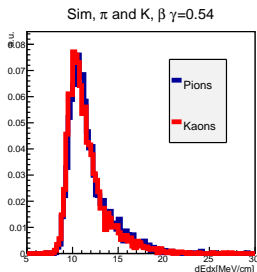
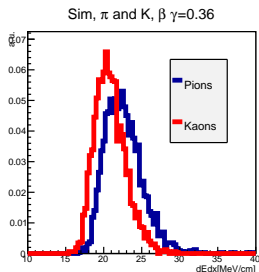
Validation issues - Charge distribution

- ▶ The collected charge is currently represented by an arbitrary and off scale number (we expect $\sim 25,000$ electron-hole pairs per MIP passing through a $300 \mu\text{m}$ Si layer):
- ▶ (Sensors characterized by different layer number and strip direction show the same pattern).



$\beta\gamma$ universality of the energy loss

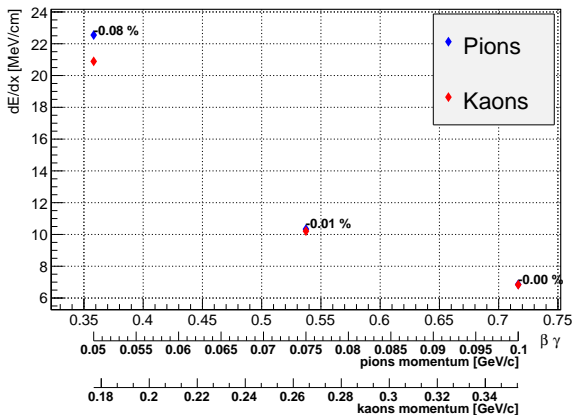
- ▶ When looking at pions and kaons, universality ceases at very low momentum ($p_\pi \sim 50$ MeV), even though:
 - ▶ Only looking at first hits (layer 3)
 - ▶ Same angular distribution of generated particles with the module
 - ▶ No deflection due to magnetic field = simple length calculation
 - ▶ Only SVD loaded in simulation geometry - are there other materials that reduce the pions momentum ?



$\beta\gamma$ universality of the energy loss

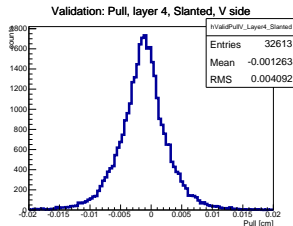
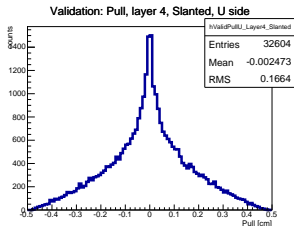
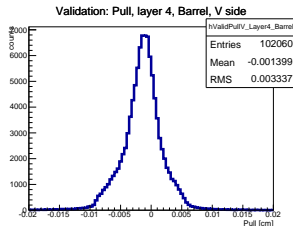
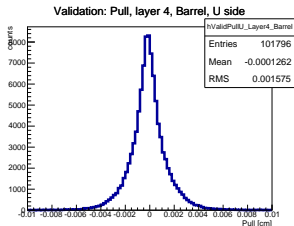
The quantitative difference between MPVs at very low momentum can be seen in this graph:

Sim: dE/dx vs $\beta\gamma$ for π and K



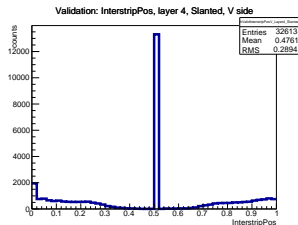
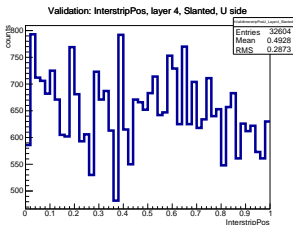
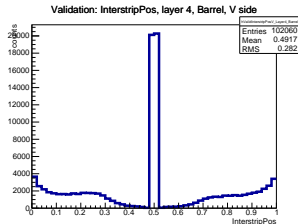
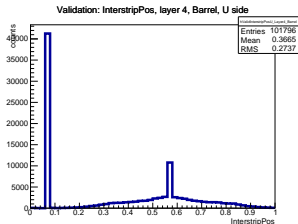
Pull distribution and spatial resolution

- ▶ The pull distribution is not symmetrical with respect to zero.
- ▶ (Sensors characterized by different layer number show the same patterns).



Interstrip position

- ▶ The eta interstrip position distribution shows several "preferred positions"
- ▶ (Sensors characterized by different layer number show the same patterns).



Calibration topics and tentative plans

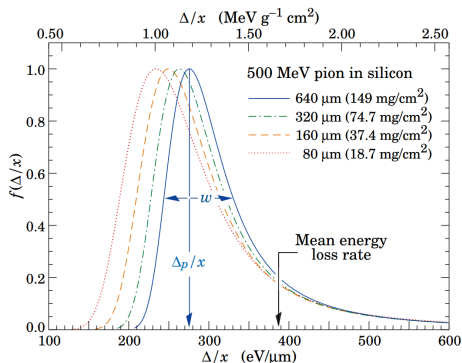
- ▶ Following up the validation work I've started to look into the calibration topics
- ▶ I will summarize several calibration techniques and their tentative implementation in the Belle II framework, regarding:
 - ▶ Charge calibration
 - ▶ Cross-talk calibration
 - ▶ Lorentz angle calibration
- ▶ Also code for the routine calibrations have to be designed (noise, pedestal levels)

Charge calibration

- ▶ Important for
 - ▶ Signal to noise optimization
 - ▶ Coherent dE/dx measurements
- ▶ Signal formation in the sensor involves two steps:
 - 1) The production of electron/hole pairs through the interaction of the charged particle passing through (Si layer specific)
 - 2) The reading and amplification of the collected charge (APV specific)
 - ▶ the calibration of this step can be done via on-chip calibration circuitry of APV chips
 - ▶ or using the APV tickmark ($175,000 e^-$)

Absolute calibration

- ▶ Calibrates also the non-uniformities in the sensors
- ▶ It can be done using cosmic muons:
 - ▶ Get ADC signal and traversed length
 - ▶ Normalize to ADC counts/unit length
 - ▶ Fit to Landau-Vavilov-Bichsel distr. to find MPV
 - ▶ Test using simulation data

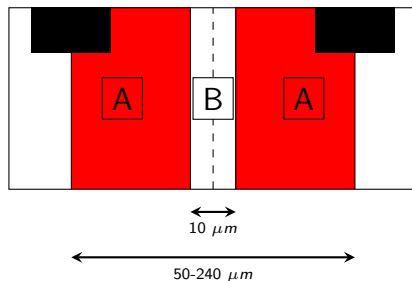


J. Beringer et al. (Particle Data Group), Phys. Rev. D86, 010001 (2012-2013)]

Eta variable

$$\eta = \frac{Q_L}{Q_L + Q_R}$$

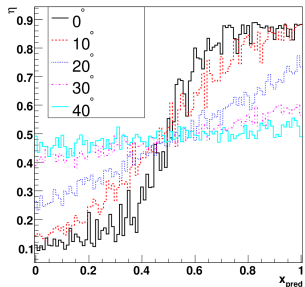
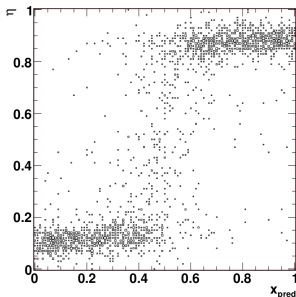
- ▶ The cross-talk happens because of capacitive coupling between strips



Adapted from R. Turchetta, *Spatial Resolution of Silicon Microstrip Detectors*, Nucl. Instr. Meth. A335 (1993)

Eta variable vs interstrip position

Plotting η vs interstrip position helps to visualize effects of cross-talk



Butz E., Ph.D thesis, *Calibration, Alignment and Long-Term Performance of the CMS Silicon Tracking Detector*, 2009

Similar variables that take into account both strips close to the seed strip can be investigated:

$$\zeta = \frac{Q_L + Q_R}{Q_L + Q_{\text{seed}} + Q_R}$$

$$\Sigma = \frac{Q_L + Q_R}{2Q_{\text{seed}}}$$

Cross talk measurement

- ▶ A tentative plan:
- ▶ Parametrizing the η distribution helps to measure the cross-talk:

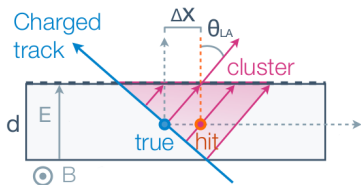
$$Q_{seed} = (1 - 2k)Q_{seed}^{raw} \qquad Q_L = Q_R = kQ_{seed}^{raw}$$

$$\eta = \frac{Q_L}{Q_L + Q_R} = \frac{k}{1 - 2k + k} = \frac{k}{1 - k}$$

- ▶ To implement the eta variable in the framework:
 - ▶ Store right and left strips charge and position in the SVDCluster class
 - ▶ Plot eta vs interstrip position
 - ▶ Extract k parameter for each strip

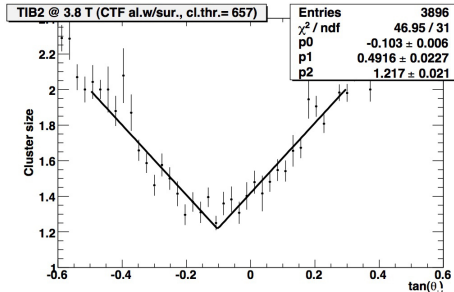
Lorentz angle measurement

- ▶ Magnetic field stretches the length of a cluster and introduces a shift of the cluster center
- ▶ Methods for measuring the Lorentz angle:
 - ▶ Find the incident angle θ that give the smallest number of strips in cluster, $\theta = \theta_{LA}$
 - ▶ Use laser to produce charges on one side of the Si layer and measure the angle of their drifting to the other side
 - ▶ Alignment setup can measure hit and cluster deposition positions



Bartosik N., *Simultaneous alignment and Lorentz angle calibration in the CMS silicon tracker using Millepede II*, EPS

HEP 2013



From CMS NOTE-2008/006

Lorentz angle measurement implementation

- ▶ A tentative plan:
- ▶ Find average cluster size for different angles
- ▶ Plot cluster size vs angle
- ▶ Fit to find intersection between two segments
- ▶ Test using simulation data

Cluster position algorithms

- ▶ Important for spatial resolution of hits
- ▶ See R. Turchetta, *Spatial Resolution of Silicon Microstrip Detectors*, Nucl. Instr. Meth. A335 (1993) 4458 [106]
- ▶ Several methods are available:
 - ▶ Eta algorithm (at small angles, i.e. small number of strips in cluster)
 - ▶ Center Of Gravity (at intermediate angles)
 - ▶ Analog Head-Tail (at large angles)

$$\frac{x_{AHT}}{p} = \frac{x_h + x_t}{2 \cdot p} + \frac{S_h - S_t}{2 \cdot S_c}$$

- ▶ 1 sided A.H.T. (at very large angles)

Position resolution algorithms

- ▶ The resolution on the hit position has a fundamental importance for the precision of the vertex reconstruction. It needs to be estimated what resolution is needed.
- ▶ What method yields the best resolution ?
 - ▶ Currently only C.O.G. and A.H.T. (size > 2) algorithms are used
 - ▶ Try the different algorithms, keeping in mind that each of them applies to a specific range of entrance angle/cluster size

Conclusion

- ▶ Validation and DQM have been written and added to the framework
- ▶ Reconstruction of energy and position of hits needs to be improved through calibrations
- ▶ I will be working on calibration algorithms for the framework
- ▶ I have surveyed a set of corrections based on previous experiments
- ▶ A tentative plan involves simulation data and then (comparison with) testbeam data

Thanks for your attention !

Any questions and/or comments ?